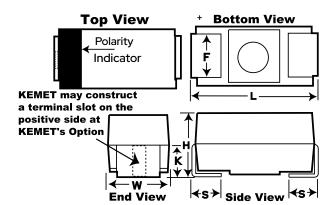


T498B106K010ZGE1K8

Obsolete

B45198P, Tantalum, MnO2 Tantalum, High Temperature, 10 uF, 10%, 10 VDC, SMD, Molded, High Temperature, N/A, 1.8 Ohms, 3528, 2.1mm



General Information	
Series	B45198P
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature
RoHS	Yes
Termination	Gold
AEC-Q200	No

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
S	0.7mm +/-0.3mm
F	2.2mm +/-0.1mm

Specifications	
Capacitance	10 uF
Capacitance Tolerance	10%
Voltage DC	10 VDC (85C), 7.97 VDC (125C), 6.7 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
ESR	1.8 Ohms (100kHz)
Leakage Current	1uA

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

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